

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1257	(438/22).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 18:43
L2	88	(438/930).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 18:44
L3	552	(438/47).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 18:44
S65	537	(257/13).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 18:43
S66	719	(LED laser light adj emitting adj (device diode)) and (boron adj phosphide BP) and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S67	63	(LED laser light adj emitting adj (device diode)) and (boron adj phosphide BP) same amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S68	45	(LED laser light adj emitting adj (device diode)) and (boron adj phosphide BP) near3 amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S69	0	PCTJP0208317	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S70	54	(LED laser light adj emitting adj (device diode)) and (boron adj (phosphorus phosphide) BP) near3 amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S71	1022	(257/94).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S72	1754	(257/103).CCLS	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S73	35	(S72 S71) and (boron adj phosphide BP)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S74	16	(S72 S71) and (boron adj phosphide BP) same amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S75	34	(LED laser light adj emitting adj (device diode)) and (boron adj phosphide BP) near3 amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S76	0	S74 not (S68 S67 S75)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S77	1	PCTJP0208317	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11

S79	6	S65 and (boron adj phosphide BP) and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S80	34	(LED laser light adj emitting adj (device diode)) and (boron adj phosphide BP) near3 amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S81	4	("20030173573" "5042043" "6069021" "6194744").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/05 14:11
S83	11	S68 not S75	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S84	29	S67 not (S68 S75)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S85	19	S70 not (S68 S67 S75)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S86	19	S73 not (S68 S67 S75)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S87	465	(takashi near3 udagawa).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S88	609	(257/96).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S89	1051	(372/44).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S90	4009	(372/45).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S91	3195	(372/46).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:11
S92	25	(S88 S89 S90 S91) and (boron adj phosphide BP)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S93	13	S92 not (S73 S70 S68 S67 S75)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S94	1	(LED laser light adj emitting adj (device diode)) and upper adj cladding near3 amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S95	12	(LED laser light adj emitting adj (device diode)) and cladding near3 amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:31
S96	58	(LED laser light adj emitting adj (device diode)) and cladding with amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11

S97	46	S96 not S95	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S98	70	(LED laser light adj emitting adj (device diode)) and (confinement cladding) with amorphous and (III adj v nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:11
S99	12	S98 not (S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:58
S100	323	(257/615).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:21
S101	6	S100 and (BP boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:22
S102	279	(257/613).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:22
S103	302	(257/76).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:42
S104	4	(257/E33.023).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:26
S105	57	(257/E33.025).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:26
S106	493	(257/E33.028).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:32
S107	0	(257/E33.033).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:22
S108	0	(257/E33.034).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 14:22
S109	27	S106 and (BP boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:33
S110	1	("3877060").PN	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/05 14:35
S111	101	(confinement cladding clad) near3 amorphous and (LED light adj emitting laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:58
S112	279	(confinement cladding clad) with amorphous and (LED light adj emitting laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:44
S113	552	(confinement cladding clad) same amorphous and (LED light adj emitting laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 14:44

S114	82	S111 not (S98 S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:24
S115	122	S112 not (S111 S98 S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:32
S116	1235	(LED laser light adj emitting adj (device diode)) and ((active light adj emitting) adj (film layer)) with amorphous and nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:34
S117	268	S113 not (S112 S111 S98 S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:33
S118	1213	S116 not (S112 S111 S98 S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:41
S119	25	S116 and (BP boron adj phosphide)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:34
S120	1197	S116 not (S119 S112 S111 S98 S68 S75 S67 S70 S73 S92 S96)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/05 15:57
S121	2	("6069021").PN	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/05 18:00


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- ☐ 1. **Simultaneous compression and amplification of ultrashort pulses at MHz repetiti**
Choi, K.-J.; Gustafson, T.L.;
Quantum Electronics, IEEE Journal of
Volume 25, Issue 12, Dec. 1989 Page(s):2441 - 2444
[AbstractPlus](#) | Full Text: [PDF\(352 KB\)](#) IEEE JNL

IEEE STD IEEE Standard

- ☐ 2. **High power ASE-free tunable laser using a Sagnac ring interferometer within the**
Fulop, L.; Souhaite, G.; Moulinet, X.; Graindorge, P.; Lefevre, H.C.;
Optical Fiber Communication Conference and Exhibit, 2001. OFC 2001
Volume 2, 2001 Page(s):TuJ6-1 - TuJ6-3 vol.2
[AbstractPlus](#) | Full Text: [PDF\(228 KB\)](#) IEEE CNF

- ☐ 3. **A ring-type device for the noninvasive measurement of arterial blood pressure**
Zheng, D.C.; Zhang, Y.T.;
Engineering in Medicine and Biology Society, 2003. Proceedings of the 25th Annual Int
Conference of the IEEE
Volume 4, 17-21 Sept. 2003 Page(s):3184 - 3187 Vol.4
[AbstractPlus](#) | Full Text: [PDF\(321 KB\)](#) IEEE CNF

- ☐ 4. **High-power operation of a 660-nm-band self-aligned stepped substrate laser**
Anayama, C.; Sugiura, K.; Furuya, A.; Tanahashi, T.;
Compound Semiconductors, 2000 IEEE International Symposium on
2-5 Oct. 2000 Page(s):401 - 406
[AbstractPlus](#) | Full Text: [PDF\(232 KB\)](#) IEEE CNF

- ☐ 5. **An overview of 4 years of kWh/kW/sub p/ monitoring at 67 sites worldwide**
Ransome, S.; Wohlgemuth, J.;
Photovoltaic Energy Conversion, 2003. Proceedings of 3rd World Conference on
Volume 3, 12-16 May 2003 Page(s):2206 - 2209 Vol.3
[AbstractPlus](#) | Full Text: [PDF\(363 KB\)](#) IEEE CNF

- ☐ 6. **50 Years after breaking the codes: interviews with two of the Bletchley Park scie**
Lee, J.A.N.; Holtzman, G.;
Annals of the History of Computing, IEEE
Volume 17, Issue 1, Spring 1995 Page(s):32 - 43
[AbstractPlus](#) | [References](#) | Full Text: [PDF\(1112 KB\)](#) IEEE JNL

- ☐ **7. Advances in multichannel MultiGbytes/s bit-parallel WDM single fiber link**
Bergman, L.A.; Yeh, C.; Morookian, J.;
Advanced Packaging, IEEE Transactions on [see also Components, Packaging and M:
Technology, Part B: Advanced Packaging, IEEE Transactions on]
Volume 24, Issue 4, Nov. 2001 Page(s):456 - 462
[AbstractPlus](#) | [References](#) | Full Text: [PDF\(118 KB\)](#) IEEE JNL

- ☐ **8. Neural network for yield estimation**
Ling Xieting; Dong Guojie;
Circuits and Systems, 1991. Conference Proceedings, China., 1991 International Conf:
16-17 June 1991 Page(s):298 - 300 vol.1
[AbstractPlus](#) | Full Text: [PDF\(132 KB\)](#) IEEE CNF

- ☐ **9. High efficiency silicon solar cells for concentrators**
Mason, N.B.; Jordan, D.; Bruton, T.M.; Summers, J.G.; Hughes, A.E.; Whitfield, G.R.;
Photovoltaic Specialists Conference, 1991., Conference Record of the Twenty Second
7-11 Oct. 1991 Page(s):124 - 127 vol.1
[AbstractPlus](#) | Full Text: [PDF\(248 KB\)](#) IEEE CNF

- ☐ **10. The achievement of 20% efficiency in a CZ silicon solar cell under concentration**
Bruton, T.M.; Heasman, K.C.; Nagle, J.P.; Russell, R.R.;
Photovoltaic Specialists Conference, 1993., Conference Record of the Twenty Third IE
10-14 May 1993 Page(s):1250 - 1251
[AbstractPlus](#) | Full Text: [PDF\(116 KB\)](#) IEEE CNF

- ☐ **11. From the brachystochrone to the maximum principle**
Sussmann, H.J.;
Decision and Control, 1996., Proceedings of the 35th IEEE
Volume 2, 11-13 Dec. 1996 Page(s):1588 - 1594 vol.2
[AbstractPlus](#) | Full Text: [PDF\(748 KB\)](#) IEEE CNF

- ☐ **12. Advances in a-Si development and manufacturing**
Arya, R.R.;
Photovoltaic Specialists Conference, 2000. Conference Record of the Twenty-Eighth IE
15-22 Sept. 2000 Page(s):19 - 24
[AbstractPlus](#) | Full Text: [PDF\(388 KB\)](#) IEEE CNF

- ☐ **13. Microvascular blood flow fluctuations during tilt table induced syncope**
Censi, F.; Strano, S.; Festinese, S.; Calcagnini, G.; Cerutti, S.;
Computers in Cardiology 2000
24-27 Sept. 2000 Page(s):465 - 468
[AbstractPlus](#) | Full Text: [PDF\(268 KB\)](#) IEEE CNF

- ☐ **14. Advances in multi-channel optical multi-gbytes/sec bit-parallel WDM single fiber**
Bergman, L.A.; Yeh, C.; Morookian, J.;
Electronic Components and Technology Conference, 2000. 2000 Proceedings. 50th
21-24 May 2000 Page(s):1504 - 1510
[AbstractPlus](#) | Full Text: [PDF\(656 KB\)](#) IEEE CNF

- ☐ **15. Interdigitated backside buried contact solar cells**
Guo, J.-H.; Cotter, J.E.;
Photovoltaic Energy Conversion, 2003. Proceedings of 3rd World Conference on
Volume 2, 12-16 May 2003 Page(s):1463 - 1466 Vol.2
[AbstractPlus](#) | Full Text: [PDF\(478 KB\)](#) IEEE CNF

- ☐ **16. Microwave-Optical Mixing with a Frequency Modulated Laser and an Unbalanced**
MAURY, G.; CABON, B.;
Lasers and Electro-optics Europe, 1996. CLEO/Europe., Conference on
8-13 Sept. 1996 Page(s):19 - 19
[AbstractPlus](#) | Full Text: [PDF\(84 KB\)](#) IEEE CNF
- ☐ **17. Heterodyne Interferometric Optical Estimation of Turbulant Liquid Media Charact**
Haudidier, N.; Cariou, J.; Lotrian, J.;
Lasers and Electro-optics Europe, 1996. CLEO/Europe., Conference on
8-13 Sept. 1996 Page(s):17 - 17
[AbstractPlus](#) | Full Text: [PDF\(100 KB\)](#) IEEE CNF
- ☐ **18. A 3D scanning system based on low-occlusion approach**
Bor-Tow Chen; Wen-Shiou Lou; Chia-Chen Chen; Hsien-Chang Lin;
3-D Digital Imaging and Modeling, 1999. Proceedings. Second International Conferenc
4-8 Oct. 1999 Page(s):506 - 515
[AbstractPlus](#) | Full Text: [PDF\(180 KB\)](#) IEEE CNF
- ☐ **19. Prospects for high efficiency silicon solar cells in thin Czochralski wafers using processes**
Bruton, T.M.; Roberts, S.; Heasman, K.C.; Russell, R.; Warta, W.; Glunz, S.W.; Dicker,
Photovoltaic Specialists Conference, 2000. Conference Record of the Twenty-Eighth IE
15-22 Sept. 2000 Page(s):180 - 183
[AbstractPlus](#) | Full Text: [PDF\(296 KB\)](#) IEEE CNF
- ☐ **20. Concepts for the manufacture of silicon solar cell modules for use in concentrati to 5/spl times/**
Bruton, T.M.; Sherborne, J.; Heasman, K.C.; Ramsdale, C.M.;
Photovoltaic Specialists Conference, 2002. Conference Record of the Twenty-Ninth IE
2002 Page(s):1366 - 1368
[AbstractPlus](#) | Full Text: [PDF\(313 KB\)](#) IEEE CNF
- ☐ **21. Investigation of thin aluminium films on the rear of monocrystalline silicon solar surface field formation**
Hartley, O.N.; Russell, R.; Heasman, K.C.; Mason, N.B.; Bruton, T.M.;
Photovoltaic Specialists Conference, 2002. Conference Record of the Twenty-Ninth IE
19-24 May 2002 Page(s):118 - 121
[AbstractPlus](#) | Full Text: [PDF\(616 KB\)](#) IEEE CNF
- ☐ **22. Environmentally friendly processes in the manufacture of Saturn solar cells**
Eager, S.; Mason, N.; Bruton, T.; Sherborne, J.; Russell, R.;
Photovoltaic Specialists Conference, 2002. Conference Record of the Twenty-Ninth IE
19-24 May 2002 Page(s):62 - 65
[AbstractPlus](#) | Full Text: [PDF\(408 KB\)](#) IEEE CNF
- ☐ **23. Towards 20% efficient silicon solar cells manufactured at 60 MWp per annum**
Bruton, T.; Mason, N.; Roberts, S.; Hartley, O.N.; Gledhill, S.; Fernandez, J.; Russell, F
Glunz, S.; Schultz, O.; Hermle, M.; Willeke, G.;
Photovoltaic Energy Conversion, 2003. Proceedings of 3rd World Conference on
Volume 1, 11-18 May 2003 Page(s):899 - 902 Vol.1
[AbstractPlus](#) | Full Text: [PDF\(359 KB\)](#) IEEE CNF
- ☐ **24. A low-voltage single-Opamp 4th-order band-pass $\Delta\Sigma$ -modulator**
Salo, T.; Lindfors, S.; Halonen, K.;
Circuits and Systems, 2001. ISCAS 2001. The 2001 IEEE International Symposium on
Volume 1, 6-9 May 2001 Page(s):352 - 355 vol. 1
[AbstractPlus](#) | Full Text: [PDF\(316 KB\)](#) IEEE CNF

**25. Electronic nose module with system on chip**

Eu-Ttum Jang; Wan-Young Chung;
Sensors, 2002. Proceedings of IEEE
Volume 2, 12-14 June 2002 Page(s):1335 - 1338 vol.2
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